Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-131-8003

Inclosure Material:

Metal

Overall Length:

0.505 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Overall Width Across Flats:

0.562 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 repetitive peak reverse voltage, peak total value and 2.0 gate trigger voltage, dc

Current Rating Per Characteristic:

40.00 milliamperes forward current, total rms preset and 175.00 milliamperes forward current, total rms minor and 360.00 amperes forward

current, average preset

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0